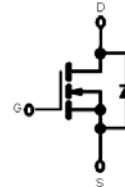
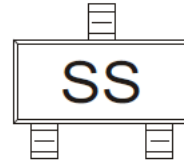


**50V N-Channel MOSFET**

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
50V	3.5Ω@10V	220mA
	6Ω@4.5V	

**Equivalent Circuit**

**FEATURE**

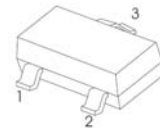
- High density cell design for extremely low  $R_{DS(on)}$
- Rugged and Reliable

**MARKING**

**APPLICATION**

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers; Display, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

**SOT-23**

1. GATE
2. SOURCE
3. DRAIN


**Maximum ratings ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

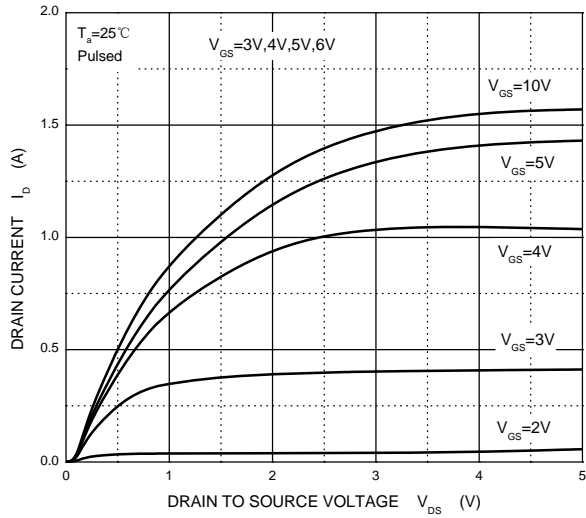
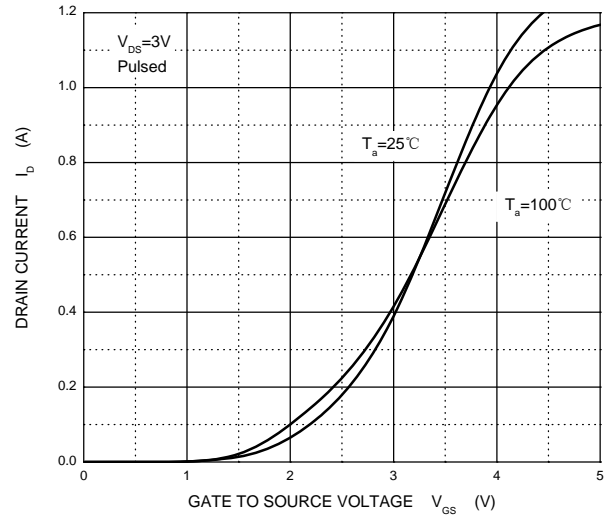
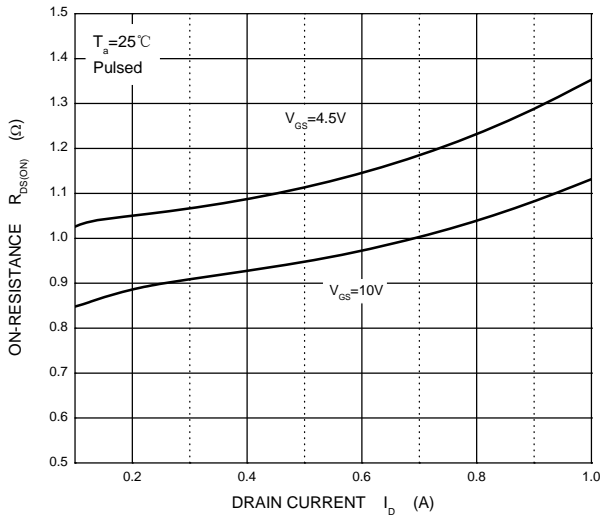
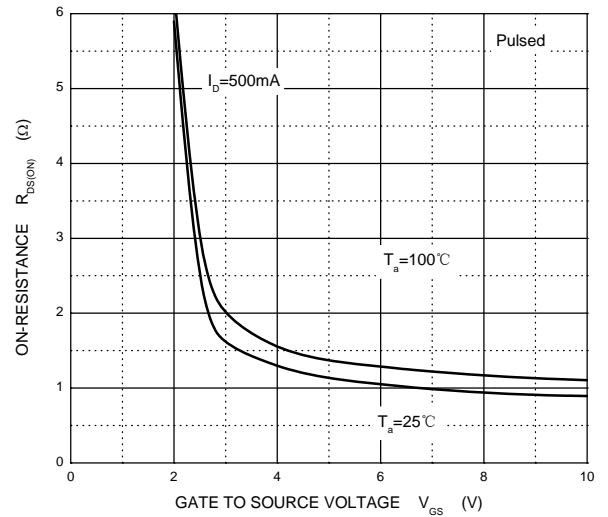
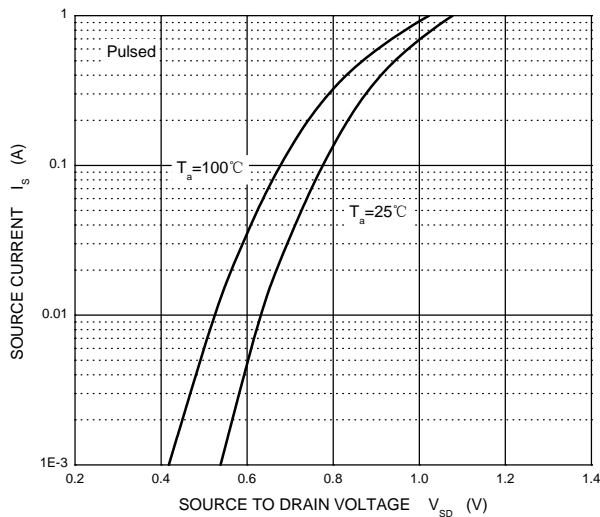
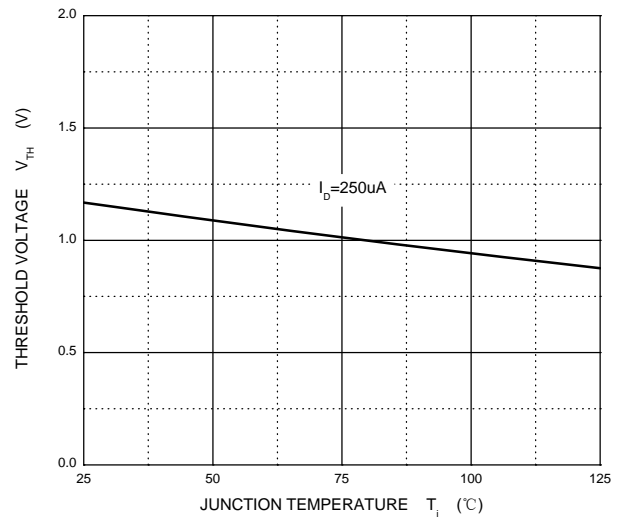
Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	50	V
Continuous Gate-Source Voltage	$V_{GSS}$	±20	
Continuous Drain Current	$I_D$	0.22	A
Power Dissipation	$P_D$	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Operating Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 ~ +150	

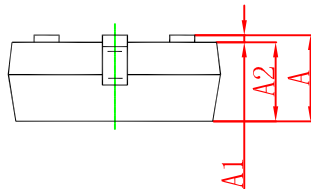
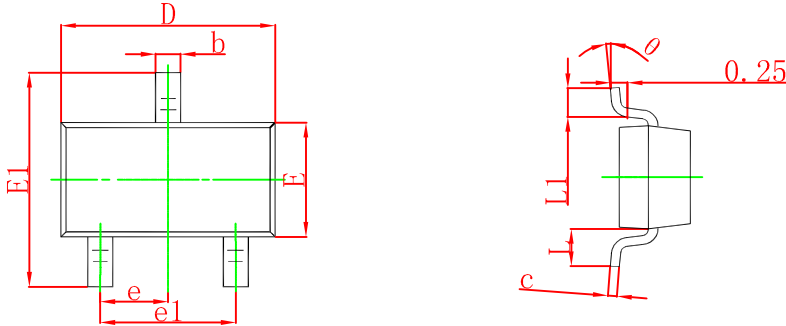
**T<sub>a</sub> = 25 °C unless otherwise specified**

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
<b>Off characteristics</b>						
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	50			V
Gate-body leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V			±100	nA
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V			0.5	μA
		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V			100	nA
<b>On characteristics</b>						
Gate-threshold voltage (note 1)	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1mA	0.80		1.50	V
Static drain-source on-resistance (note 1)	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.22A			3.50	Ω
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 0.22A			6	
Forward transconductance (note 1)	g <sub>FS</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.22A	0.12			S
<b>Dynamic characteristics (note 2)</b>						
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz		27		pF
Output capacitance	C <sub>oss</sub>			13		
Reverse transfer capacitance	C <sub>rss</sub>			6		
<b>Switching characteristics</b>						
Turn-on delay time (note 1,2)	t <sub>d(on)</sub>	V <sub>DD</sub> = 30V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.29A, R <sub>GEN</sub> = 6Ω			5	ns
Rise time (note 1,2)	t <sub>r</sub>				18	
Turn-off delay time (note 1,2)	t <sub>d(off)</sub>				36	
Fall time (note 1,2)	t <sub>f</sub>				14	
<b>Drain-source body diode characteristics</b>						
Body diode forward voltage (note 1)	V <sub>SD</sub>	I <sub>S</sub> = 0.44A, V <sub>GS</sub> = 0V			1.4	V

**Notes:**

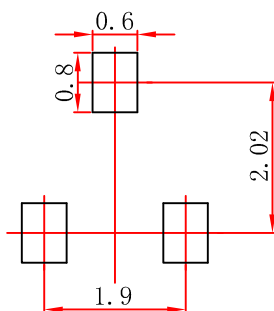
1. Pulse Test ; Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
2. These parameters have no way to verify.

**Output Characteristics**

**Transfer Characteristics**

 **$R_{DS(ON)}$  —  $I_D$** 

 **$R_{DS(ON)}$  —  $V_{GS}$** 

 **$I_S$  —  $V_{SD}$** 

**Threshold Voltage**




Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

### SOT-23 Suggested Pad Layout



**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFET](#) category:*

*Click to view products by [Shenzhen JingYang](#) manufacturer:*

Other Similar products are found below :

[IRFD120](#) [JANTX2N5237](#) [BUK455-60A/B](#) [MIC4420CM-TR](#) [VN1206L](#) [NDP4060](#) [SI4482DY](#) [IPS70R2K0CEAKMA1](#) [SQD23N06-31L-GE3](#)  
[TK16J60W,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [DMN1053UCP4-7](#) [SQJ469EP-T1-GE3](#) [NTE2384](#) [DMC2700UDMQ-7](#)  
[DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)  
[STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN6022SSD-13](#) [DMN13M9UCA6-7](#) [DMTH10H4M6SPS-13](#) [DMN2990UFB-7B](#)  
[IPB80P04P405ATMA2](#) [2N7002W-G](#) [MCAC30N06Y-TP](#) [MCQ7328-TP](#) [NTMC083NP10M5L](#) [NVMFS2D3P04M8LT1G](#) [BXP7N65D](#)  
[BXP4N65F](#) [AOL1454G](#) [WMJ80N60C4](#) [BXP2N20L](#) [BXP2N65D](#) [BXT1150N10J](#) [BXT1700P06M](#) [TSM60NB380CP](#) [ROG](#) [RQ7L055BGTCR](#)  
[DMNH15H110SK3-13](#) [SLF10N65ABV2](#) [BSO203SP](#) [BSO211P](#)